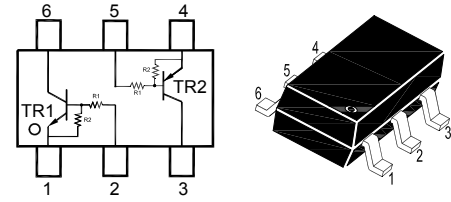


■ **NPN/PNP Silicon Epitaxial Planar Digital Transistor**
for switching and interface circuit and drivecircuit applications

■ **Features**

- Transistors with different polarity and built-in bias resistors R1 and R2
- Simplification of circuit design
- Reduces number of components and board space



1. Emitter 2. Base 3. Collector
4. Emitter 5. Base 6. Collector

■ **Simplified outline(SOT-363)**

■ **Absolute Maximum Ratings at T_a = 25°C (TR1)**

Parameter	Symbol	Value	Unit
Collector Base Voltage	V _{CBO}	50	V
Collector Emitter Voltage	V _{CEO}	50	V
Emitter Base Voltage	V _{EBO}	6	V
Collector Current	I _C	100	mA

■ **Absolute Maximum Ratings at T_a = 25°C (TR2)**

Parameter	Symbol	Value	Unit
Collector Base Voltage	-V _{CBO}	50	V
Collector Emitter Voltage	-V _{CEO}	50	V
Emitter Base Voltage	-V _{EBO}	6	V
Collector Current	-I _C	100	mA

■ **Absolute Maximum Ratings at T_a = 25°C (TR1 and TR2)**

Parameter	Symbol	Value	Unit
Total Power Dissipation	P _{tot}	200	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	- 55 to + 150	°C

■ Characteristics at $T_a = 25^\circ\text{C}$ (TR1:NPN)

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_{CE} = 5\text{ V}$, $I_C = 10\text{ mA}$	h_{FE}	80	-	-	-
Collector Base Cutoff Current at $V_{CB} = 50\text{ V}$	I_{CBO}	-	-	100	nA
Collector Emitter Cutoff Current at $V_{CE} = 50\text{ V}$	I_{CEO}	-	-	500	nA
Emitter Base Cutoff Current at $V_{EB} = 6\text{ V}$	I_{EBO}	0.081	-	0.15	mA
Collector Emitter Saturation Voltage at $I_C = 5\text{ mA}$, $I_B = 0.25\text{ mA}$	V_{CEsat}	-	-	0.3	V
Input Voltage (OFF) at $V_{CE} = 5\text{ V}$, $I_C = 100\text{ }\mu\text{A}$	$V_{I(OFF)}$	0.5	-	1	V
Input Voltage (ON) at $V_{CE} = 0.2\text{ V}$, $I_C = 5\text{ mA}$	$V_{I(ON)}$	0.7	-	1.8	V
Gain Bandwidth Product at $V_{CE} = 10\text{ V}$, $I_C = 5\text{ mA}$, $f = 100\text{ MHz}$	f_T	-	250	-	MHz

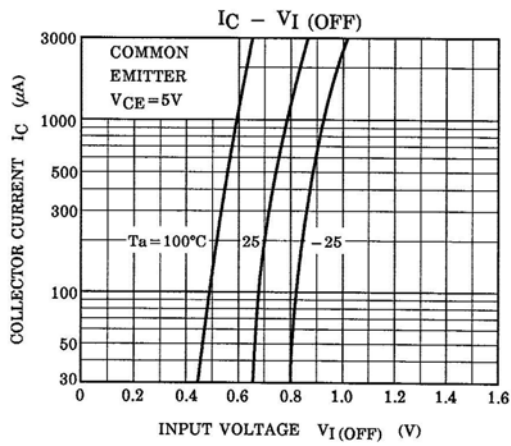
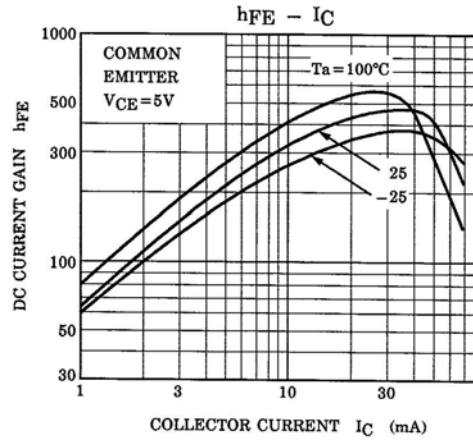
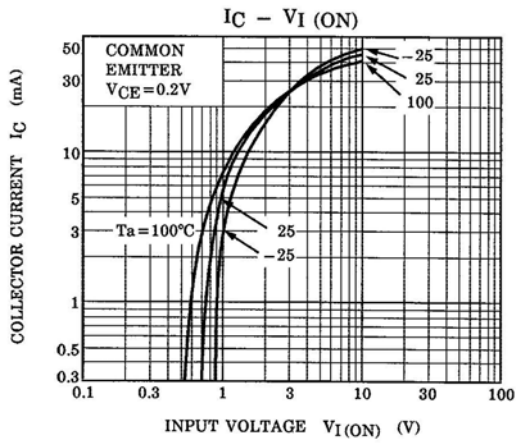
Characteristics at $T_a = 25^\circ\text{C}$ (TR2:PNP)

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $-V_{CE} = 5\text{ V}$, $-I_C = 10\text{ mA}$	h_{FE}	80	-	-	-
Collector Base Cutoff Current at $-V_{CB} = 50\text{ V}$	$-I_{CBO}$	-	-	100	nA
Collector Emitter Cutoff Current at $-V_{CE} = 50\text{ V}$	$-I_{CEO}$	-	-	500	nA
Emitter Base Cutoff Current at $-V_{EB} = 6\text{ V}$	$-I_{EBO}$	0.081	-	0.15	mA
Collector Emitter Saturation Voltage at $-I_C = 5\text{ mA}$, $-I_B = 0.25\text{ mA}$	$-V_{CEsat}$	-	-	0.3	V
Input Voltage (OFF) at $-V_{CE} = 5\text{ V}$, $-I_C = 100\text{ }\mu\text{A}$	$-V_{I(OFF)}$	0.5	-	1	V
Input Voltage (ON) at $-V_{CE} = 0.2\text{ V}$, $-I_C = 5\text{ mA}$	$-V_{I(ON)}$	0.7	-	1.8	V
Gain Bandwidth Product at $-V_{CE} = 10\text{ V}$, $-I_C = 5\text{ mA}$, $f = 100\text{ MHz}$	f_T	-	200	-	MHz

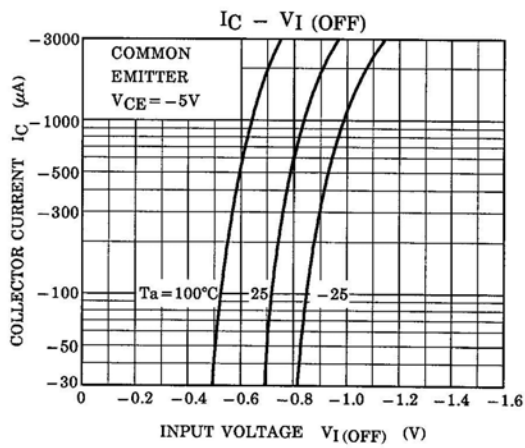
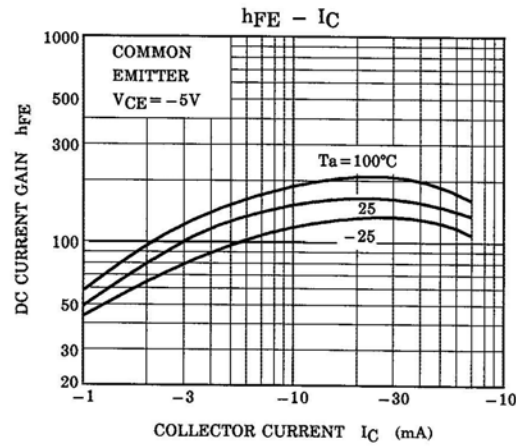
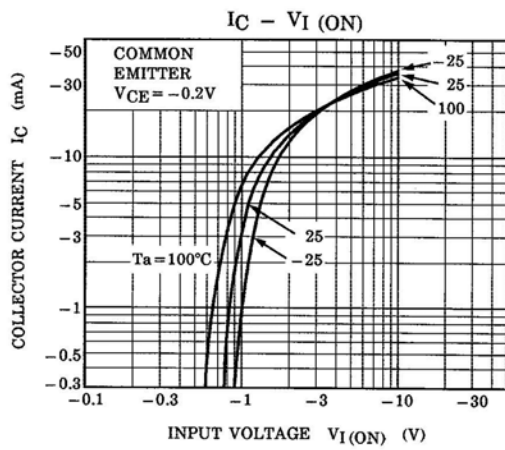
Characteristics at $T_a = 25^\circ\text{C}$ (TR1 and TR2)

Input Resistance	R_1	7	10	13	K Ω
Resistance Ratio	R_1/R_2	0.191	0.213	0.232	-

TR1

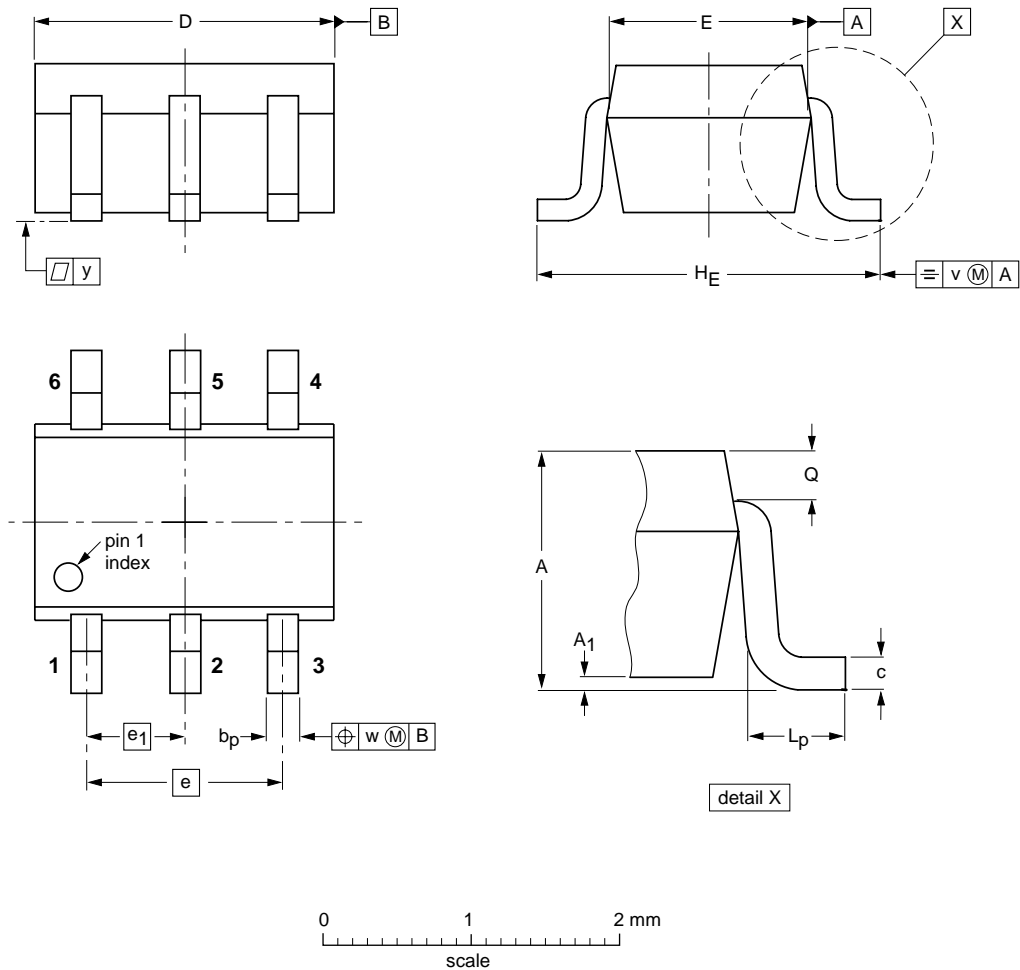


TR2



Package Outline

SOT-363



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w	y
mm	1.1 0.8	0.1	0.30 0.20	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.25 0.15	0.2	0.2	0.1

Summary of Packing Options

Package	Package Description	Packing Quantity	Industry Standard
SOT-363	Tape/Reel, 7" reel	3000	EIA-481-1